



Integrated  
Circuit  
Systems, Inc.

# ICS840031I

## FEMTOCLOCKS™ CRYSTAL-TO-LVCMOS/LVTTL CLOCK GENERATOR

### GENERAL DESCRIPTION



The ICS840031I is an IEEE 1394b Clock Generator and a member of the HiPerClocks™ family of high performance devices from ICS. The ICS840031I uses a 24.576MHz crystal to synthesize 98.304MHz. The ICS840031I has excellent phase jitter performance, from 12KHz – 20MHz integration range. The ICS840031I is packaged in a small 8-pin SOIC, making it ideal for use in systems with limited board space.

### FEATURES

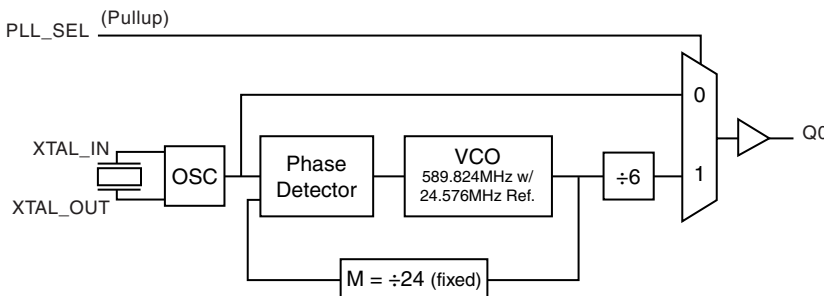
- (1) LVCMOS/LVTTL output
- Crystal oscillator interface designed for a 24.576MHz, 18pF parallel resonant crystal
- Output frequency: 98.304MHz (typical)
- VCO range: 490MHz to 640MHz
- RMS phase jitter @ 98.304MHz, using a 24.576MHz crystal (12KHz - 20MHz): 0.75ps (typical)
- RMS phase noise at 98.304MHz (typical)
 

Offset	Noise Power
100Hz .....	-103.3 dBc/Hz
1KHz .....	-126.2 dBc/Hz
10KHz .....	-134.2 dBc/Hz
100KHz .....	-132.9 dBc/Hz
- 3.3V core/1.8V output operating supply
- Lead-Free fully RoHS compliant
- -40°C to 85°C ambient operating temperature

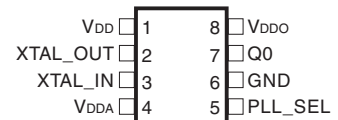
### FREQUENCY TABLE

Inputs	Output Frequency
Crystal Frequency (MHz)	(MHz)
24.576	98.304

### BLOCK DIAGRAM



### PIN ASSIGNMENT



### ICS840031I

8-Lead SOIC

3.90mm x 4.90mm x 1.37mm package body

M Package

Top View



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## FEMTOCLOCKS™ CRYSTAL-TO-LVCMOS/LVTTL CLOCK GENERATOR

**TABLE 1. PIN DESCRIPTIONS**

Number	Name	Type		Description
1	V <sub>DD</sub>	Power		Core supply pin.
2, 3	XTAL_OUT, XTAL_IN	Input		Crystal oscillator interface. XTAL_IN is the input, XTAL_OUT is the output.
4	V <sub>DDA</sub>	Power		Analog supply pin.
5	PLL_SEL	Input	Pullup	PLL select pin. LVCMOS/LVTTL interface levels.
6	GND	Power		Power supply ground.
7	Q0	Output		Single-ended clock output. LVCMOS/LVTTL interface levels.
8	V <sub>DDO</sub>	Power		Output supply pin.

NOTE: *Pullup* refers to internal input resistors. See Table 2, Pin Characteristics, for typical values.

**TABLE 2. PIN CHARACTERISTICS**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C <sub>IN</sub>	Input Capacitance			4		pF
C <sub>PD</sub>	Power Dissipation Capacitance	V <sub>DD</sub> = V <sub>DDA</sub> = 3.465V, V <sub>DDO</sub> = 1.89V		18		pF
R <sub>PULLUP</sub>	Input Pullup Resistor			51		kΩ
R <sub>OUT</sub>	Output Impedance			10		Ω



**ABSOLUTE MAXIMUM RATINGS**

Supply Voltage, $V_{DD}$	4.6V
Inputs, $V_I$	-0.5V to $V_{DD} + 0.5V$
Outputs, $V_O$	-0.5V to $V_{DDO} + 0.5V$
Package Thermal Impedance, $\theta_{JA}$	112.7°C/W (0 lfpm)
Storage Temperature, $T_{STG}$	-65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

**TABLE 3A. POWER SUPPLY DC CHARACTERISTICS,  $V_{DD} = V_{DDA} = 3.3V \pm 5\%$ ,  $V_{DDO} = 1.8V \pm 5\%$ ,  $T_A = -40^\circ C$  TO  $85^\circ C$**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{DD}$	Core Supply Voltage		3.135	3.3	3.465	V
$V_{DDA}$	Analog Supply Voltage		3.135	3.3	3.465	V
$V_{DDO}$	Output Supply Voltage		1.71	1.8	1.89	V
$I_{DD}$	Power Supply Current				55	mA
$I_{DDA}$	Analog Supply Current				12	mA
$I_{DDO}$	Output Supply Current				5	mA

**TABLE 3B. LVCMOS/LVTTL DC CHARACTERISTICS,  $V_{DD} = V_{DDA} = 3.3V \pm 5\%$ ,  $V_{DDO} = 1.8V \pm 5\%$ ,  $T_A = -40^\circ C$  TO  $85^\circ C$**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{IH}$	Input High Voltage		2		$V_{DD} + 0.3$	V
$V_{IL}$	Input Low Voltage		-0.3		0.8	V
$I_{IH}$	Input High Current	PLL_SEL $V_{DD} = V_{IN} = 3.465V$			5	$\mu A$
$I_{IL}$	Input Low Current	PLL_SEL $V_{DD} = 3.465V, V_{IN} = 0V$	-150			$\mu A$
$V_{OH}$	Output High Voltage; NOTE 1		1.5			V
$V_{OL}$	Output Low Voltage; NOTE 1				0.4	V

NOTE 1: Outputs terminated with 50Ω to  $V_{DD}/2$ . See Parameter Measurement Information Section, "3.3V/1.8V Output Load Test Circuit".

**TABLE 4. CRYSTAL CHARACTERISTICS**

Parameter	Test Conditions	Minimum	Typical	Maximum	Units
Mode of Oscillation		Fundamental			
Frequency	$F_{SEL} = 1$	20.417	24.576	26.667	MHz
Equivalent Series Resistance (ESR)				50	Ω
Shunt Capacitance				7	pF

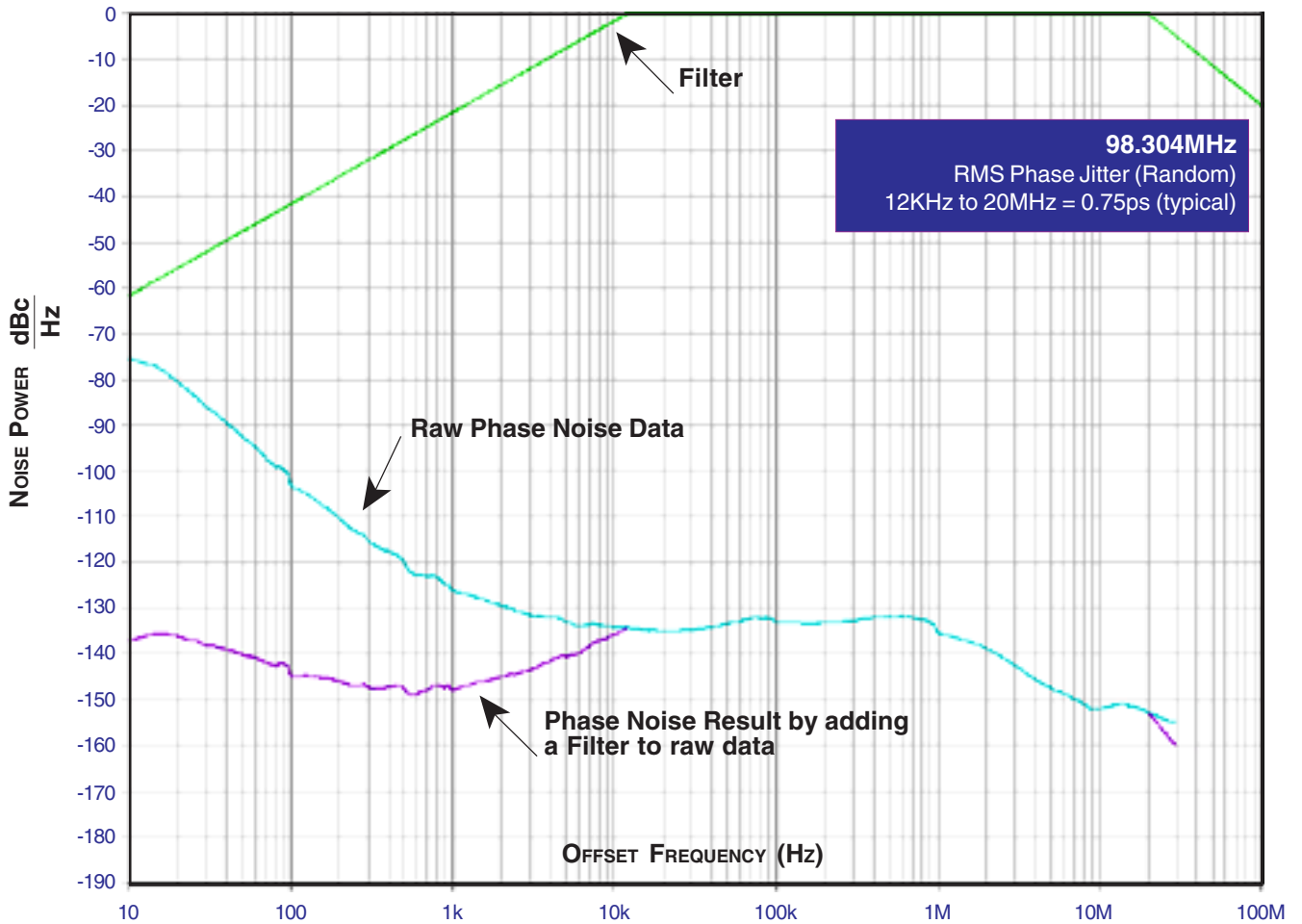
**TABLE 5. AC CHARACTERISTICS,  $V_{DD} = V_{DDA} = 3.3V \pm 5\%$ ,  $V_{DDO} = 1.8V \pm 5\%$ ,  $T_A = -40^\circ C$  TO  $85^\circ C$**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$f_{OUT}$	Output Frequency		81.67	98.304	106.67	MHz
$f_{jit}(\emptyset)$	RMS Phase Jitter (Random); NOTE 1	$f_{OUT} = 98.304MHz$ , (12KHz to 20MHz)		0.75		ps
$t_R / t_F$	Output Rise/Fall Time	20% to 80%	0.2		1	ns
odc	Output Duty Cycle		46		54	%

NOTE 1: Please refer to the Phase Noise Plot.

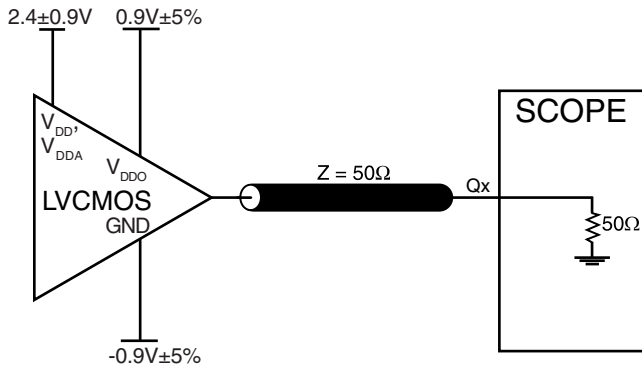


**TYPICAL PHASE NOISE AT 98.304MHz**

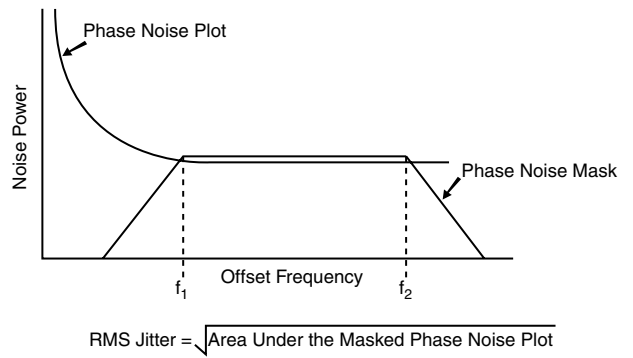




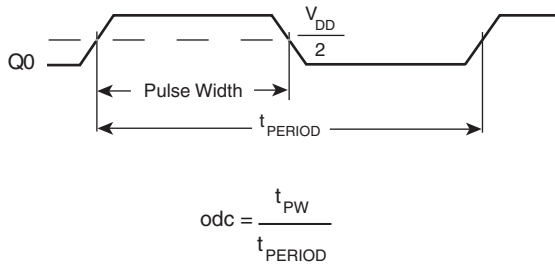
**PARAMETER MEASUREMENT INFORMATION**



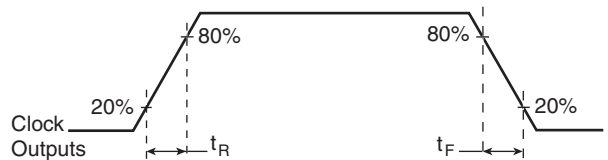
**3.3V/1.8V OUTPUT LOAD AC TEST CIRCUIT**



**RMS PHASE JITTER**



**OUTPUT DUTY CYCLE/PULSE WIDTH/PERIOD**



**OUTPUT RISE/FALL TIME**



## APPLICATION INFORMATION

### POWER SUPPLY FILTERING TECHNIQUES

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. The ICS840031I provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL.  $V_{DD}$ ,  $V_{DDA}$ , and  $V_{DDO}$  should be individually connected to the power supply plane through vias, and bypass capacitors should be used for each pin. To achieve optimum jitter performance, power supply isolation is required. *Figure 1* illustrates how a  $10\Omega$  resistor along with a  $10\mu\text{F}$  and a  $.01\mu\text{F}$  bypass capacitor should be connected to each  $V_{DDA}$  pin.

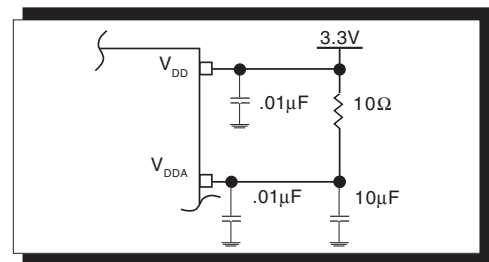


FIGURE 1. POWER SUPPLY FILTERING

### CRYSTAL INPUT INTERFACE

The ICS840031I has been characterized with  $18\text{pF}$  parallel resonant crystals. The capacitor values, C1 and C2, shown in *Figure 2* below were determined using a  $24.576\text{MHz}$ ,  $18\text{pF}$

parallel resonant crystal and were chosen to minimize the ppm error. The optimum C1 and C2 values can be slightly adjusted for different board layouts.

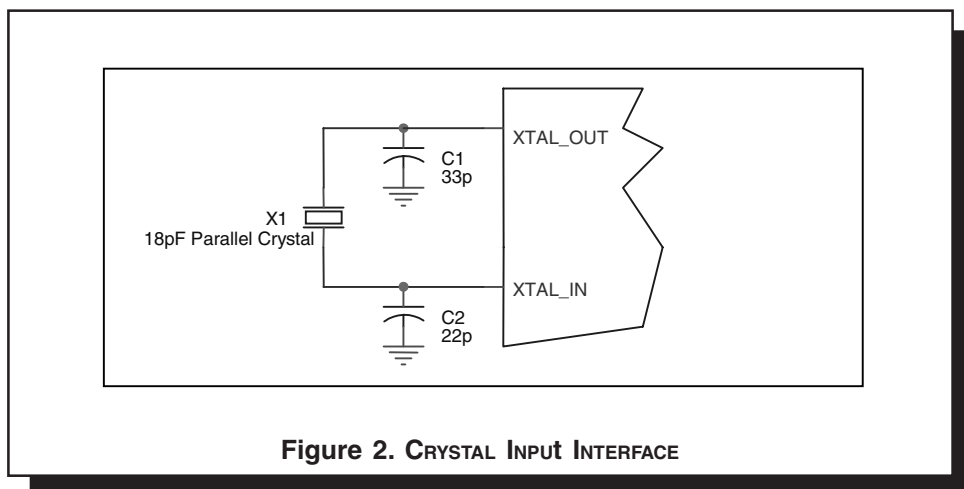


Figure 2. CRYSTAL INPUT INTERFACE



## APPLICATION SCHEMATIC EXAMPLE

Figure 3 shows a schematic example of the ICS840031I. In this example, a series termination, one of LVCMOS termination approaches, is shown. Additional LVCMOS termination approaches are shown in the LVCMOS Termination Application Note. In this

example, an 18pF parallel resonant crystal is used. The C1=22pF and C2=33pF are approximate values for frequency accuracy. The C1 and C2 may be slightly adjusted for optimizing frequency accuracy.

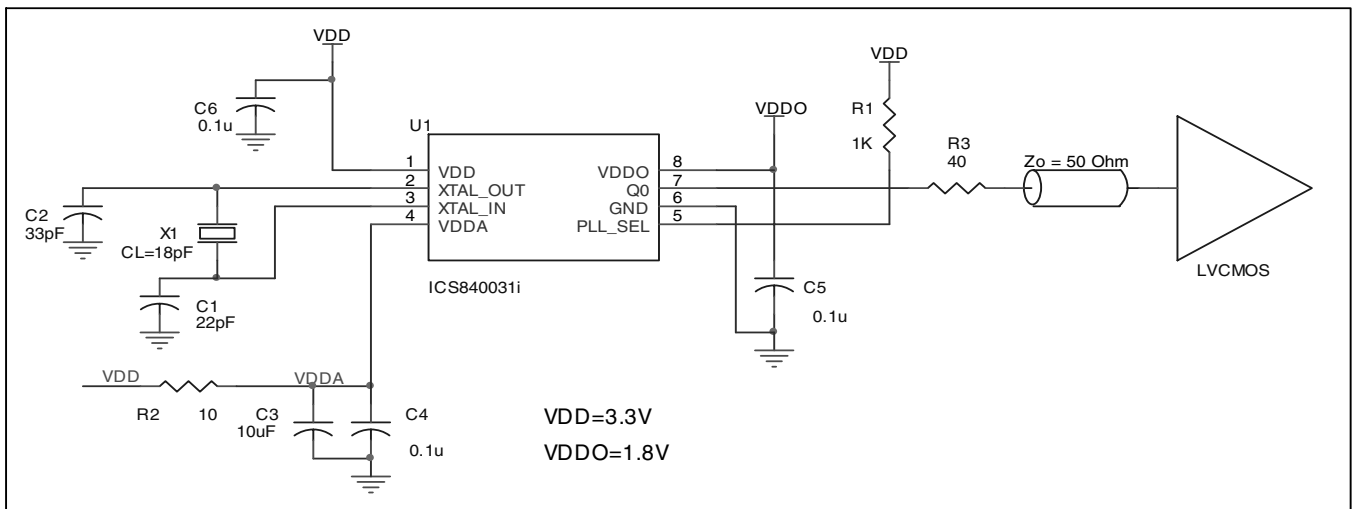


FIGURE 3. ICS840031I APPLICATION SCHEMATIC EXAMPLE

## RELIABILITY INFORMATION

TABLE 6.  $\theta_{JA}$  vs. AIR FLOW TABLE FOR 8 LEAD SOIC

$\theta_{JA}$ by Velocity (Linear Feet per Minute)			
	0	200	500
Single-Layer PCB, JEDEC Standard Test Boards	153.3°C/W	128.5°C/W	115.5°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	112.7°C/W	103.3°C/W	97.1°C/W

**NOTE:** Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

### TRANSISTOR COUNT

The transistor count for ICS840031I is: 1787



PACKAGE OUTLINE - M SUFFIX FOR 8 LEAD SOIC

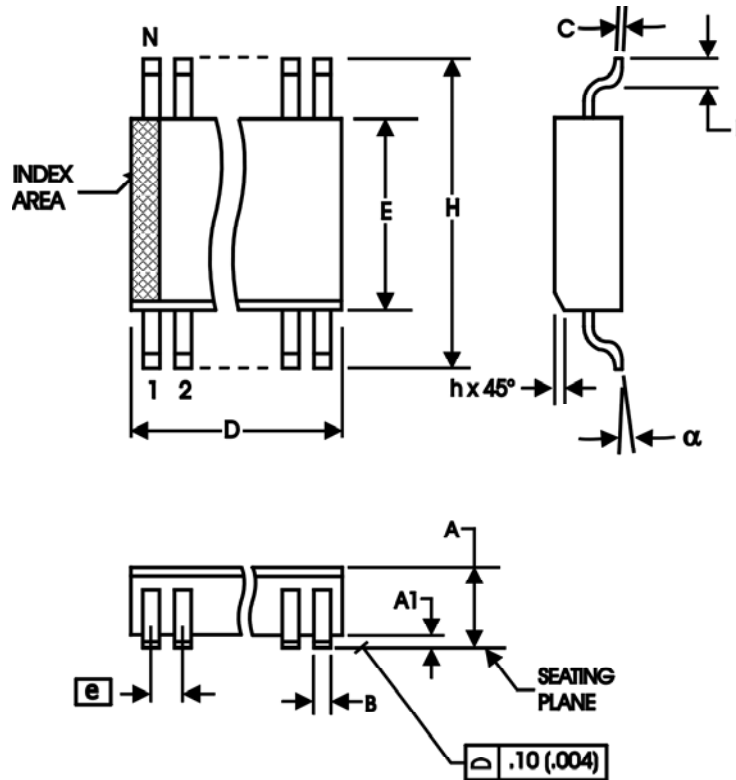


TABLE 7. PACKAGE DIMENSIONS

SYMBOL	Millimeters	
	MINIMUM	MAXIMUM
N	8	
A	1.35	1.75
A1	0.10	0.25
B	0.33	0.51
C	0.19	0.25
D	4.80	5.00
E	3.80	4.00
e	1.27 BASIC	
H	5.80	6.20
h	0.25	0.50
L	0.40	1.27
α	0°	8°

Reference Document: JEDEC Publication 95, MS-012





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**TABLE 8. ORDERING INFORMATION**

Part/Order Number	Marking	Package	Count	Temperature
ICS840031AMI	840031AI	8 lead SOIC	tube	-40°C to 85°C
ICS840031AMIT	840031AI	8 lead SOIC	2500 tape & reel	-40°C to 85°C
ICS840031AMILF	40031AIL	8 lead "Lead-Free" SOIC	tube	-40°C to 85°C
ICS840031AMILFT	40031AIL	8 lead "Lead-Free" SOIC	2500 tape & reel	-40°C to 85°C

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